



Product Summary

BV _{DSS}	R _{DS(ON)} max	Ι _D T _C = +25°C	
40V	4.7mΩ @ V _{GS} = 10V	100A	

Description and Applications

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

- Engine Management Systems
- **Body Control Electronics**
- **DC-DC** Converters

40V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low Input Capacitance
- Low Input/Output Leakage
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TO220-3 •
- Case Material: Molded Plastic, "Green" Molding Compound, UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram Below
- Weight: 1.85 grams (Approximate)

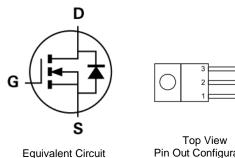


TO220-3

Top View



Bottom View



Pin Out Configuration

Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMT4005SCT	TO220-3	50 pieces/tube			
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

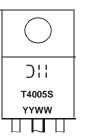
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Dil = Manufacturer's Marking T4005S = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Drain-Source Voltage	V _{DSS}	40	V	
Gate-Source Voltage	V _{GSS}	±20	V	
Continuous Drain Current (Nata C)	$T_{\rm C}$ = +25°C		100	•
Continuous Drain Current (Note 6)	$T_C = +70^{\circ}C$	ID	85	A
Maximum Continuous Body Diode Forward Current (Note 6)	T _C = +25°C	Is	85	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	160	A	
Avalanche Current, L=0.1mH	I _{AS}	32.5	A	
Avalanche Energy, L=0.1mH	E _{AS}	52.8	mJ	

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 5)		$R_{ extsf{ heta}JA}$	52.8	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	104	W
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	1.2	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

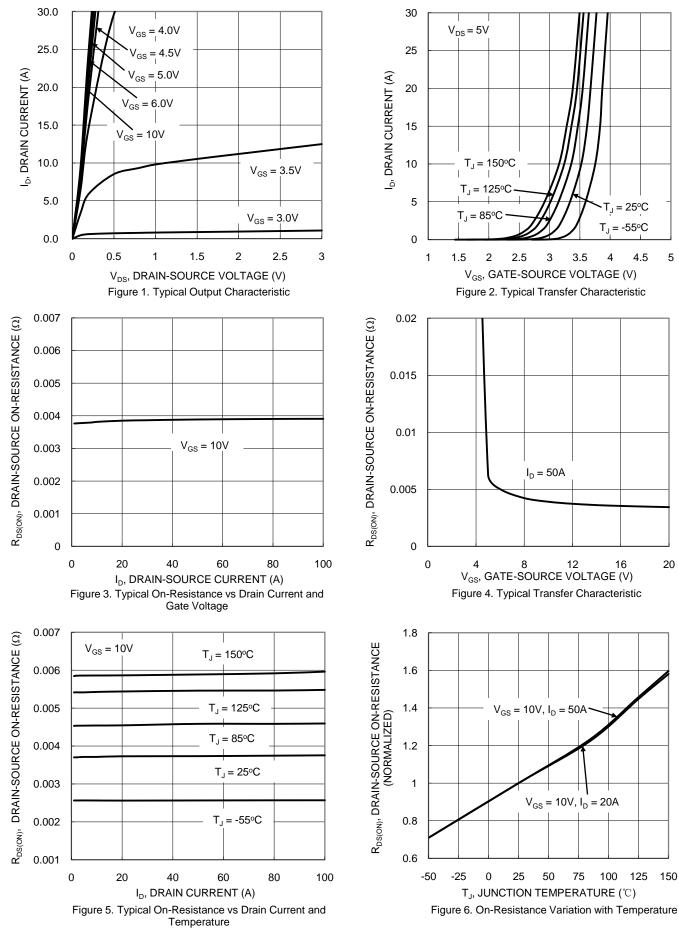
Characteristic	Cumula al	Min	Turn	Max	11.4	Test Condition	
	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	40	—	—	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}		_	1	μA	$V_{DS} = 32V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}		—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	2	_	4	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R _{DS(ON)}		3.8	4.7	mΩ	$V_{GS} = 10V, I_D = 50A$	
Diode Forward Voltage	V _{SD}	_	_	1.2	V	$V_{GS} = 0V, I_{S} = 50A$	
DYNAMIC CHARACTERISTICS (Note 8)	-		-			-	
Input Capacitance	Ciss	_	3062	_			
Output Capacitance	Coss	_	902		pF	$V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz	
Reverse Transfer Capacitance	Crss	_	179	_			
Gate Resistance	R _G	_	0.67		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 10V)	Qq	_	49.1				
Gate-Source Charge	Q _{gs}	_	10.3		nC	$V_{DD} = 20V, I_D = 50A,$	
Gate-Drain Charge	Q _{qd}	_	13			V _{GS} = 10V	
Turn-On Delay Time	t _{D(ON)}	_	8.7			V_{DD} = 20V, V_{GS} = 10V, I_D = 50A, R_G = 3 Ω	
Turn-On Rise Time	t _R	_	6.8				
Turn-Off Delay Time	t _{D(OFF)}		18.6		ns		
Turn-Off Fall Time	tF		7.3		1		
Reverse Recovery Time	t _{RR}		31.8	_	ns		
Reverse Recovery Charge	Q _{RR}		26.5	—	nC	$I_F = 50A, di/dt = 100A/\mu s$	

 Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on infinite heat sink. Notes:

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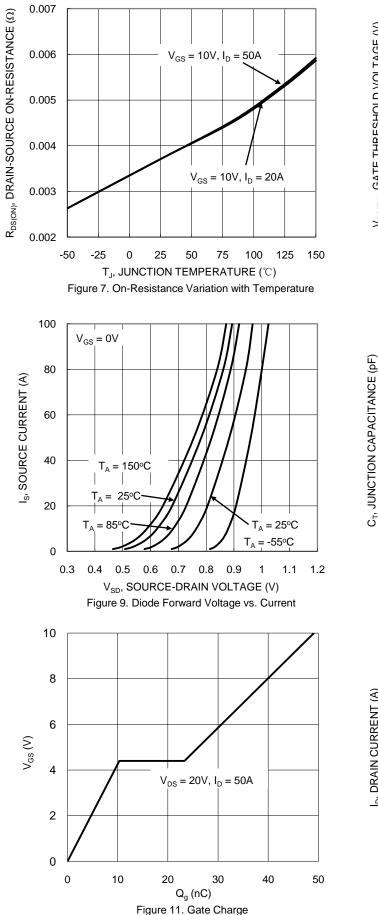


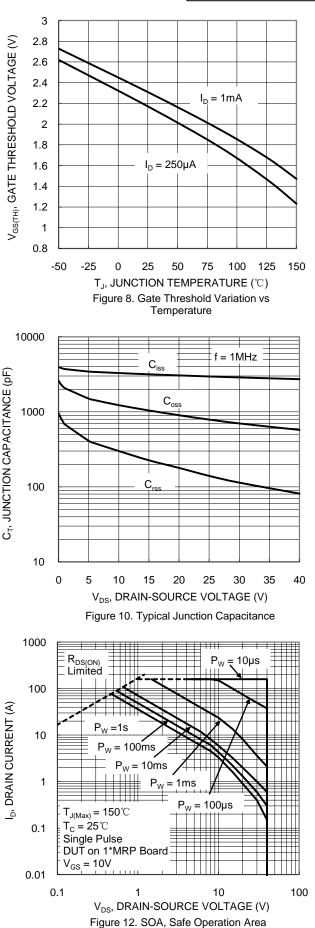
DMT4005SCT



DMT4005SCT Document number: DS38889 Rev. 1 - 2

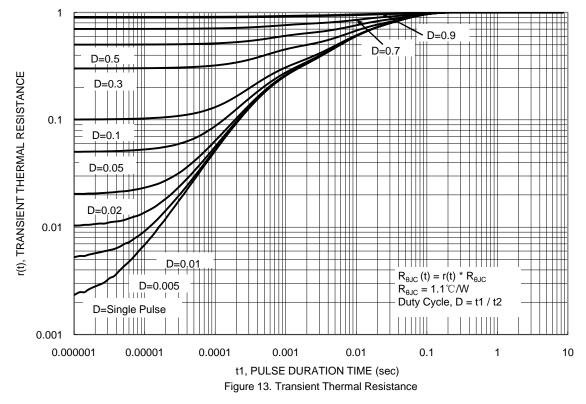






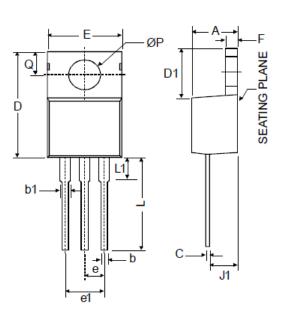
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO220-3 Min Dim Max 3.55 4.85 А b 0.51 1.14 b1 1.14 1.78 С 0.31 1.14 D 14.20 16.50 D1 5.84 6.86 Ε 9.70 10.70 е 2.79 2.99 4.83 5.33 e1 F 0.51 1.40 J1 2.03 2.92 L 12.72 14.72 3.66 L1 6.35 Ρ 3.53 4.09 2.54 Q 3.43 All Dimensions in mm

TO220-3



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